DECLARATION AND POWER OF ATTORNEY

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

LOW TRIGGER VOLTAGE ESD NMOSFET TRIPLE-WELL CMOS DEVICES

2011		TODIEI IRRIED WEED ONIOD D	Z VIOLO	
the specification of which: (check one)				
is attached hereto.□ was filed on	, as Application S	erial Noand	was amended on	
I hereby state that I have reviewed amendment referred to above.	and understand the contents of the	he above identified specification, inc	luding the claims, as amended by any	
I acknowledge the duty to disclose in Regulations, § 1.56.	formation which is material to the	patentability of this application in acc	ordance with Title 37, Code of Federal	
	ed below any foreign application		on(s) for patent or inventor's certificate naving a filing date before that of the	
Prior Foreign Application(s):				
Number	Country	Day/Month/Year	Priority Claimed	
I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, § 1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:				
Prior U.S. Applications:				
Serial No.	Filing Date	Status		
I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.				
and Trademark Office connected the (Reg. No. 27,712), William D. Sabo	erewith: Anthony J. Canale (Reg. o (Reg. No. 27,465), Robert A. W	No. 51,526), Mark F. Chadurjian (Falsh (Reg. No. 26,516), Richard A. H	and transact all business in the Patent Reg. No. 30,739), Richard M. Kotulak Ienkler (Reg. No. 39,220), Christopher 8,753), All attorneys and/or agents at	
Send all correspondence to: Ge	eorge R. Pettit, Esq. Cu	stomer No. 42,221		
Direct Telephone Calls to: Ge	eorge R.Pettit, (302)658-9141			
	C·V- how.		Date: 04/07/04	
Citizenship: Inc Post Office Address: San	dia ma os Pasidanca			

(2)	Inventor: Robert J. Gauthier, Jr.	
	Signature: Met J. Frust	Date: 4/7/04
	Residence: Rural Route 2, Box 3286-1, Hinesburg, Vermont 05461 Citizenship: United States Post Office Address: Same as Residence	
(3)	Inventor: Mujahid Muhammad	
	Signature: Pols	Date:
	Residence: 83 River Road, Apt. F, Essex Junction, Vermont 05452 Citizenship: India Post Office Address: Same as Residence	
(4)	Inventor: Christopher S. Putnam	1
	Signature: Charles Shran	Date: 4/7/04
	Residence: 426 Turkey Lane, Hinesburg, Vermont 05461 Citizenship: United States Post Office Address: Same as Residence	·